

BCR602 hot plug IC with dimming

60 V linear LED controller IC for dimmable LED applications with ripple suppression, overtemperature and hot plug protection

Features

- Supply voltage 8 V to 60 V,
- Supports use of NPN bipolar transistors and NMOS MOSFETS,
- AC supply voltage ripple suppression,
- Dimming at pin MFIO
 - 3% analog dimming of LED current by resistor R_{set} or DC voltage,
 - 1% PWM dimming of LED current by PWM signals,
- R_{set} functionality at pin *MFIO*,
- LED current precision ±3%.

Protection features

- Hot plug protection,
- Overtemperature protection.

Target applications

- LED light engines/modules,
- LED replacement lamps.

Advantages with respect to discrete solutions

- Low BOM count,
- Lower assembly cost,
- Smaller form factor,
- Higher reliability due to less parts and soldering joints.

Product validation

Qualified for industrial applications according to the relevant tests of JEDEC47/20/22.

Device information

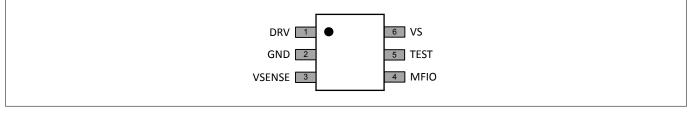


Figure 1

Pin configuration







Description

Table 1Part information

Туре	Package	Configuration	Marking code
60V Linear Current Control Chip BCR602	PG-SOT23-6	n.a.	602

Description

BCR602 is a linear LED controller IC regulating the LED current by means of an external driver transistor. BCR602 supports use of NPN bipolar transistors and NMOSFETs to cover a wide LED current and power range up to several hundred mA. The LED current is fully scalable by dimensioning an external current sense resistor. BCR602 suppresses the voltage ripple of the power supply driving a constant LED current for better light quality. The LED current can be dimmed by resistors as well as analog or digital PWM voltages connected to the Multi Function Input Output (MFIO) pin. The embedded hot plug protection allows plug in and plug out of any LED load during operation.

The overtemperature protection will dim the LED current if the BCR602 junction temperature threshold is exceeded. In this case the LED current will be reduced to 30% of the nominal current. Once the junction temperature drops below the temperature hysteresis nominal LED current is resumed.

The BCR602 is a perfect fit for LED applications by combining small form factor with low cost. Through its higher integration, BOM savings and ensuring long lifetime of LEDs, this controller has many advantages compared to discrete solutions.



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Pin configuration

1 Pin configuration

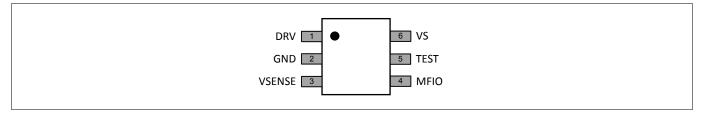


Figure 2 Pin configuration

Table 2	Pin co	configuration					
Pin no.	Pin name	Pin type	Function				
1	DRV	Output	Driver output to control base or gate of the external transistor				
2	GND	GND	IC ground				
3	VSENSE	Input	Measurement of V _{sense} voltage				
4	MFIO	Input	Multifunctional IO for resistive (via external R _{set}), DC voltage and PWM voltage dimming				
5	TEST	Output	For test purpose, it must not be directly connected to ground. It is recommended to leave <i>TEST</i> pin open or attach a resistor to ground > 1 MΩ.				
6	VS	Input	Supply voltage				

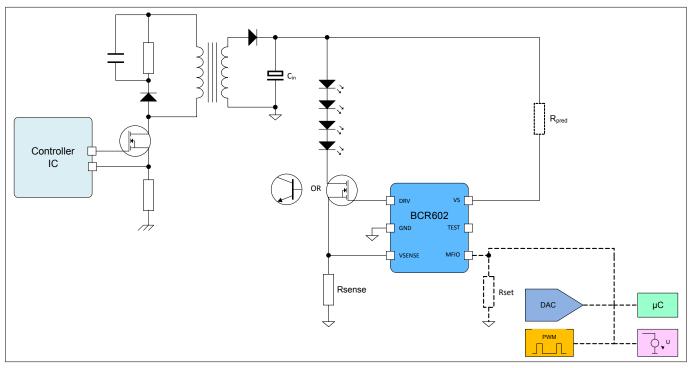


Functional description

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Functional description

Typical application circuit





Application hints

1. External driver transistors

BCR602 is able to drive NPN transistors as well as NMOSFETs. NPN transistors can be used for LED currents up to several 100 mA while NMOSFETs are preferable for high LED currents. The smaller current using BJTs is caused by the DC current gain value h_{FE} value of the used BJT. E.g. a typical h_{FE} of 75 limits the application to a maximum below 750 mA.

2. Supply voltage of BCR602

To drive higher output currents into an external NPN driver transistor it might be necessary to limit the supply voltage of BCR602 significantly below 60 V to reduce power dissipation inside the IC. This can be achieved either by adding a series resistor (R_{pred}) between supply voltage and VS pin of BCR602 or by operating BCR602 by an auxiliary winding of the power supply providing a lower IC supply voltage as e.g. 8 V or higher.

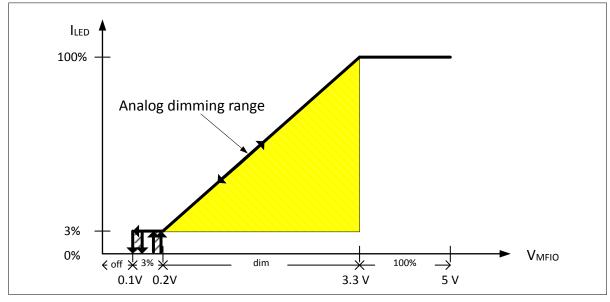
Dimming mechanism

Application MFIO input signal can be a DC voltage or a pulse width modulated digital signal for dimming of the LED current.

1. Pure DC dimming: input voltage V_{MFIO} at pin *MFIO*. Continuous dimming from 3% dimming level up to 100% is embedded into a 100% ceiling plateau and an hysteresis range to off. Static dimming to a fixed value can be done via the resistor R_{set}.



Functional description





- 2. Pure PWM dimming: The PWM duty cycle at pin *MFIO* defines the dimming level. The PWM voltage amplitude corresponding to LED on must be in the voltage range specified by *V*_{MFIO, 100%} and PWM voltage amplitude corresponding to LED off must be in the voltage range specified by *V*_{MFIO, off}. The LED current is PWM modulated according to the PWM input signal.
- **3.** For resistive dimming using *R*_{set} and internal MFIO current, the internal pull-down has to be taken into account. For proper dimensioning refer to *Figure 5*.

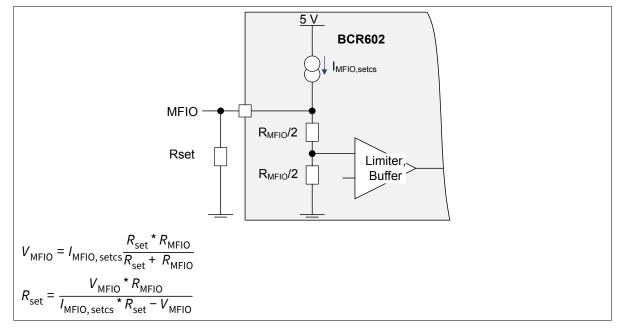


Figure 5

R_{set} dimensioning for resistor dimming

- $R_{MFIO.typical} = 285 \text{ k}\Omega$,
- $I_{MFIO,setcs,typical} = 20 \ \mu A.$



Thermal characteristics

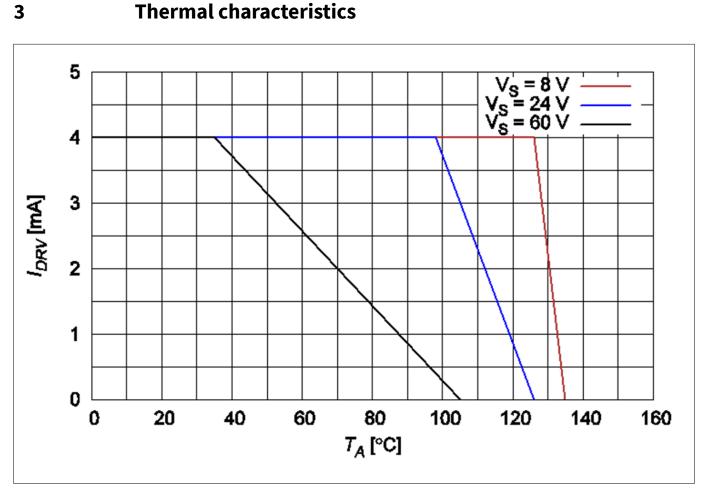


Figure 6 Maximum permitted effective output source current out of pin *DRV* into external driver transistor for a design example of 4 mA DC driver

The maximum permitted effective driver source current shown in *Figure 6* can be calculated by following equation:

$$I_{\text{DRV}} = \frac{\frac{T_{\text{OTP, on, min}} - T_A}{R_{\text{thJA}}} - V_S \cdot I_s}{V_S} = \frac{T_{\text{OTP, on, min}} - T_A}{V_S \cdot R_{\text{thJA}}} - I_S$$

The equation considers the power dissipation caused by the current consumption of the IC itself. If the driver current exceeds the calculated threshold the lower spec limit of the overtemperature protection will be exceeded and OTP might be triggered.

T_{OTP, on, min}

The lower spec limit of the overtemperature protection threshold should not be exceeded to avoid triggering the OTP.



Absolute maximum ratings

4 Absolute maximum ratings

Parameter Symbol Values Unit Note or test condition Min. Тур. Max. °C $T_{\rm J}$ -40 160 Junction temperature _ _ V Supply voltage $V_{\rm S}$ 0 65 _ _ V Input voltage at pin MFIO 0 5.0 $V_{\rm MFIO}$ _ _ 0 Input voltage at pin 3.6 V V_{sense} _ _ VSENSE P_{tot} Power dissipation 360 $V_{\rm S} = 60 \text{ V}, I_{\rm S} = 2 \text{ mA}, I_{\rm DRV}$ _ _ mW = -4 mA 2 kV HBMacc. to JEDEC **ESD** robustness V_{ESD,HBM} _ JS-001 500 ٧ CDM acc. to JEDEC V_{ESD,CDM} _ JS-002

Table 3Absolute maximum ratings

Attention: Stresses above the maximum values listed here may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Maximum ratings are absolute ratings. Exceeding only one of these values may cause irreversible damage to the integrated circuit.

Table 4Maximum thermal resistance

Parameter	Symbol	Values			Unit	Note or test condition
		Min.	Тур.	Max.		
Thermal resistance junction to ambient	R _{thJA}	-	-	290	K/W	JEDEC 1s0p (JESD 51-3) footprint w/o extra cooling area
	R _{thJA,100}	-	-	200	K/W	JEDEC 1s0p (JESD 51-3) with 100 mm ² cooling area
	R _{thJA,300}	-	-	180	K/W	JEDEC 1s0p (JESD 51-3) with 300 mm ² cooling area



Operating conditions

5 Operating conditions

Table 5Operating conditions

Parameter	Symbol	Values			Unit	Note or test condition
		Min.	Тур.	Max.	-	
Junction temperature	TJ	-40	_	160	°C	-
Supply voltage	Vs	0	-	60	V	-



Electrical characteristics

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Electrical characteristics

Note: All parameters are measured at $T_A = 25^{\circ}$ C, VS = 45 V unless otherwise specified.

*Note: I*_{LED,target} *current is the undimmed current at a VSENSE voltage drop of 400 mV typical.*

	aracterist					
Parameter	Symbol	Values			Unit	Note or test condition
		Min.	Тур.	Max.		
IC system	1	1				
Supply voltage	Vs	8	-	60	V	Operational supply voltage range
Supply voltage brownin	V _{S,bi}	-	-	8	V	-
Supply voltage brownout	V _{S,bo}	6.7	-	-	V	_
Supply current	I _S	-2.2	-	-	mA	$I_{\text{DRV, source}} = 0 \text{ A}$
Sense voltage	V _{sense}	388	400	412	mV	Closed loop reference voltage of pin VSENSE, I _{LED} = V _{sense} / R _{sense}
LED current accuracy						
LED current accuracy	I _{LED, acc} / I _{LED, acc,} target	-3	-	3	%	Closed loop LED current accuracy without dimming at V _{MFIO} = 3.3 V
Driver						
Driver source current capability, DC	I _{DRV,} source	10	-	-	mA	Source current range of pin <i>DRV</i> to drive NPN base/NMOS gate
Driver sink current capability, DC	I _{DRV, sink}	-	-	-10	mA	Sink current range of pin <i>DRV</i> to discharge NPN base/NMOS gate
Driver source voltage	V _{DRV}	4.5	5	5.5	V	Max. output voltage of pin <i>DRV</i>
Dimming analog						
MFIO turn-off range	V _{MFIO, off}	0	-	0.1	V	Threshold for analog dimming to off
MFIO turn-on range	V _{MFIO,on}	0.17	-	0.195	V	Threshold for analog dimming to on
MFIO full current range	V _{MFIO,} 100%	3.3	-	5	V	MFIO range always at 100% I _{LED}
MFIO output source current	I _{MFIO,} setcs	18	20	22	μA	For R _{SET} < 10 kΩ, in parallel internal pull- down R _{MFIO} connected, refer to <i>Figure 5</i>
MFIO output voltage	V _{MFIO,} setcs	-	4.2	-	V	MFIO output voltage at MFIO open



Electrical characteristics

Parameter	Symbol		Values		Unit	Note or test condition
		Min.	Тур.	Max.		
MFIO pull-down resistor	R _{MFIO}	228	285	342	kΩ	Internal pull-down resistor at pin <i>MFIO</i>
MFIO dimming range	V _{MFIO,} dim	0.2	-	3.3	V	Analog dimming range of the LED current
Analog LED dimming	I _{LEDmin,} _{ana} / I _{LEDmin,} target	-	3	_	%	Minimum dimming LED current level at <i>MFIO</i> _{dim} = 0.15 V
LED current chip to chip variation at selected dimming level		-20	-	20	%	Max variation at minimum MFIO dimming level
		-10		10		Max variation for dimming level higher than minimum
Dimming PWM ¹⁾						
MFIO PWM frequency	f _{PWM}	-	_	3.5	kHz	Maximum supported PWM frequency at pin <i>MFIO</i> , external switch Q _g = 8.7 nC
Minimum PWM duty cycle	I _{LEDmin,} PWM / I _{LED,} target	-	1	_	%	Minimum LED current dimming ratio by a PWM signal connected to pin <i>MFIO</i> , external switch Q _g = 8.7 nC
Minimum pulse width	t _{duty, on}	2.9	-	_	μs	Minimum LED PWM digital pulse width between 0 V and 3.3 V, external switch Q _g = 8.7 nC
Overtemperature prote	ction OTP					
Overtemperature protection threshold, turn on	T _{OTP, on}	140	-	155	°C	Junction threshold temperature to trigger overtemperature protection in standby, / _{DRV} = 0 mA and <i>VS</i> = 45 V
Overtemperature protection threshold, turn off	T _{OTP, off}	120	-	135	°C	Junction threshold temperature to exit overtemperature protection in standby, / _{DRV} = 0 mA and <i>VS</i> = 45 V

Table 6 DC characteristics (continued)

¹ Tested at 0.5 kHz and 3.5 kHz.



Electrical characteristics

Table 6DC characteristics (continued)

Parameter	Symbol	Values			Unit	Note or test condition
		Min.	Тур.	Max.		
Sense voltage in OTP case	V _{sense,} OTP / V _{sense,} target	-	30	-	%	Reduction factor at pin VSENSE (nominal 400 mV) if OTP has been triggered, I _{LED, OTP} = V _{sense,OTP} / R _{sense}
Overtemperature protection hysteresis	T _{OTP, Hys}	-	20	-	°C	-
Hot plug						
Hot plug <i>VSENSE</i> threshold	V _{sense, HP}	-	8	-	mV	<i>VSENSE</i> level at which hot plug event is detected



Package information

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Package information

Note: Dimensions in mm.

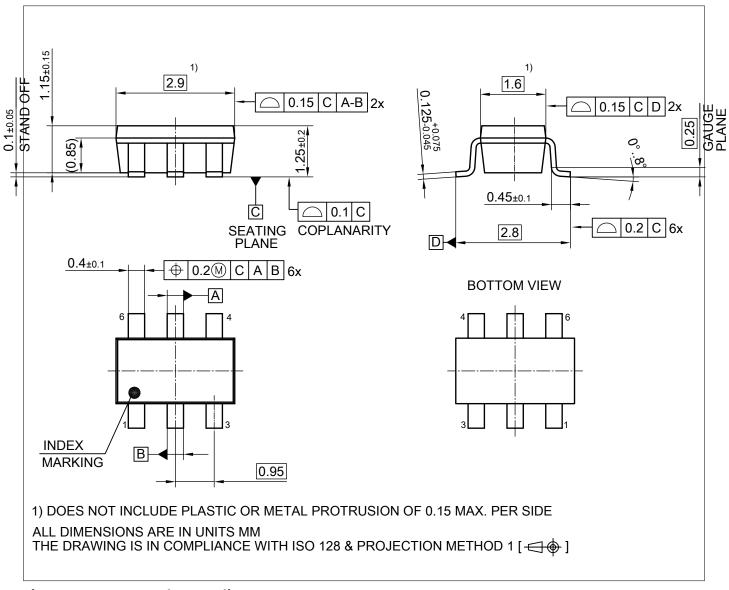


Figure 7

Package outline PG-SOT23-6



References

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Revision history

Document version	Date of release	Description of changes			
v1.0	2018-11-23	Public release			
v1.1	2018-12-03	Parameter update			

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Edition 2018-12-3 Published by Infineon Technologies AG 81726 Munich, Germany

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Document reference IFX-rjb1519293082418

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